

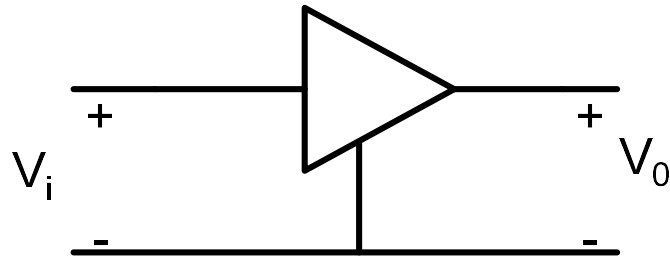
ESC201T : Introduction to Electronics

Lecture 25: Amplifiers-1

B. Mazhari
Dept. of EE, IIT Kanpur

“Amplification is the heartbeat of Electronics”

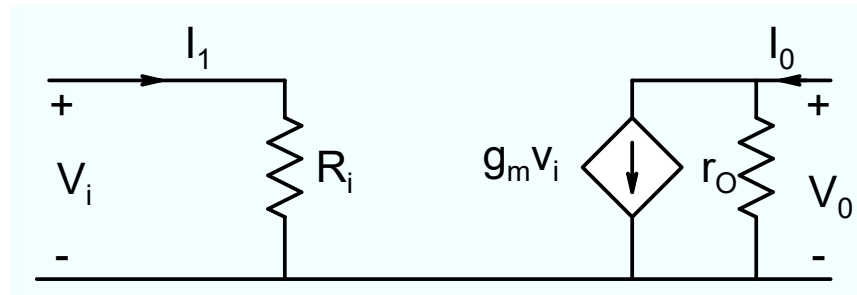
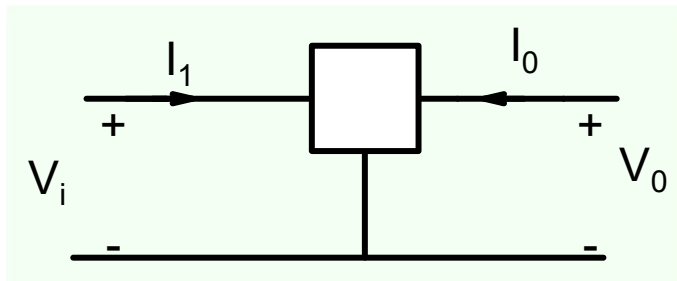
Voltage Amplification



$$V_o = G \times V_i$$

$$G > 1 \text{ and constant}$$

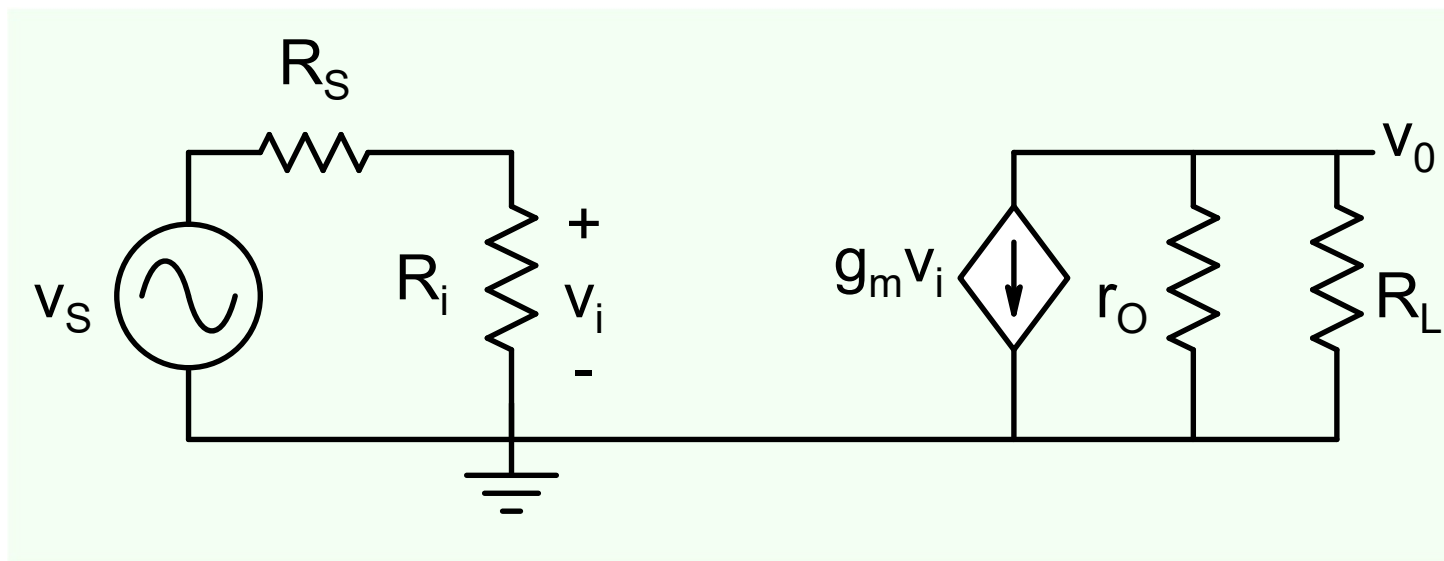
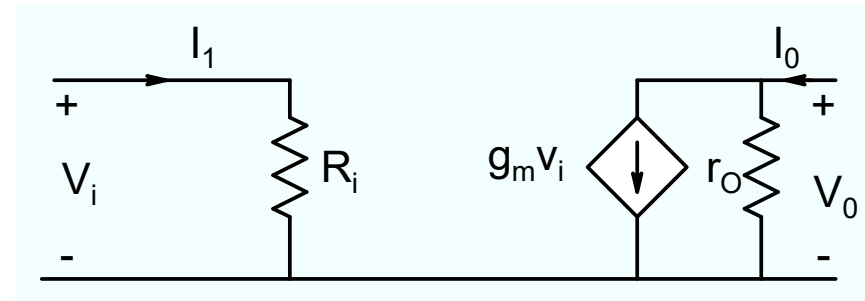
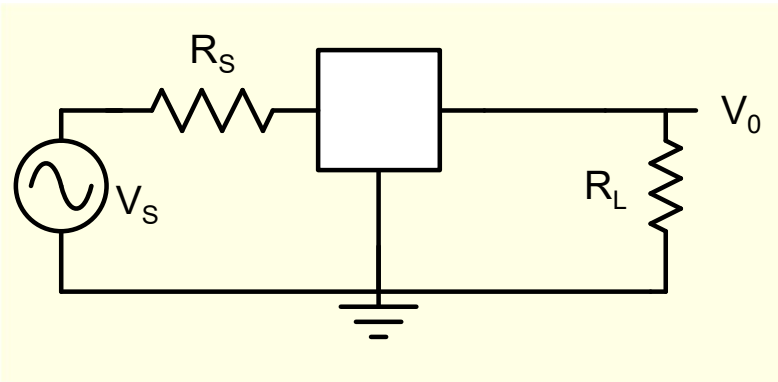
Consider a 3-terminal unilateral linear device

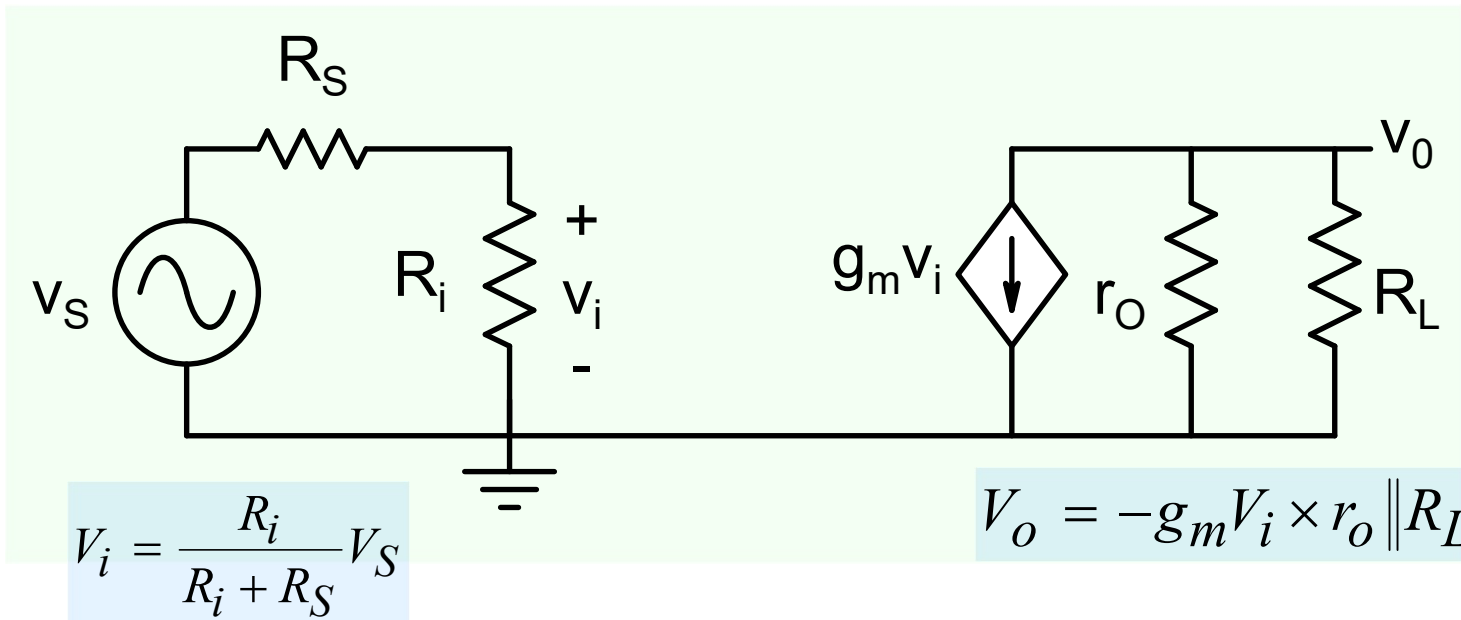


$$R_i = \text{input resistance} = V_i / I_i \quad ; \quad \text{Transconductance: } g_m = \left. \frac{I_o}{V_i} \right|_{V_o=0}$$

$$\text{Output conductance: } g_o = 1/r_o = \left. \frac{I_o}{V_o} \right|_{V_i=0}$$

Voltage Amplifier





$$A_V = \frac{V_o}{V_s} = -g_m r_o \times \frac{R_L}{r_o + R_L} \times \frac{R_i}{R_i + R_S}$$

$$|A_V| \leq g_m \times r_o$$

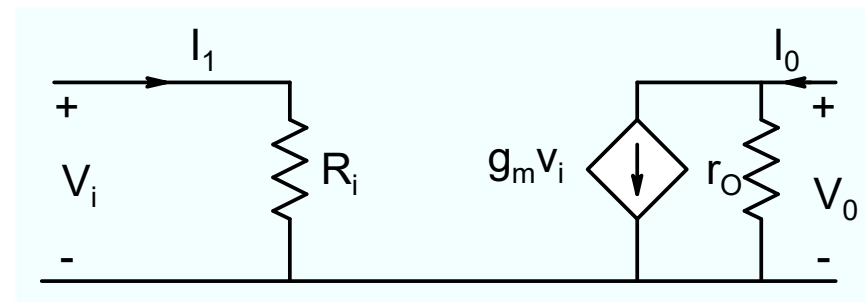
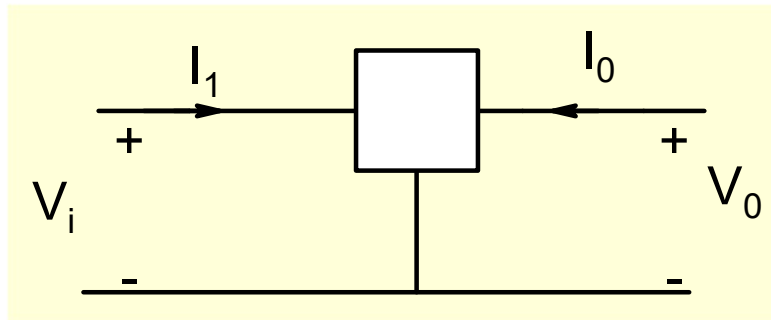
Necessary Condition for Voltage Amplification : $g_m \times r_o > 1$

Voltage Amplification

$$g_m r_o \gg 1$$

$$g_m \gg g_o$$

Transconductance \gg Output Conductance



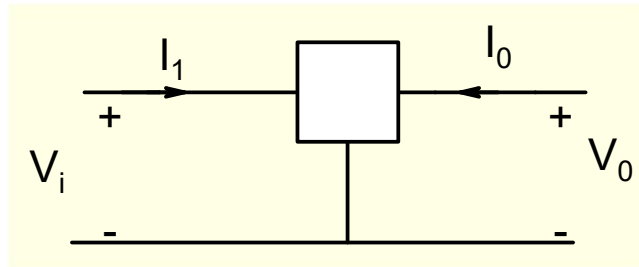
Transistor

Transistor

Trans-resistor

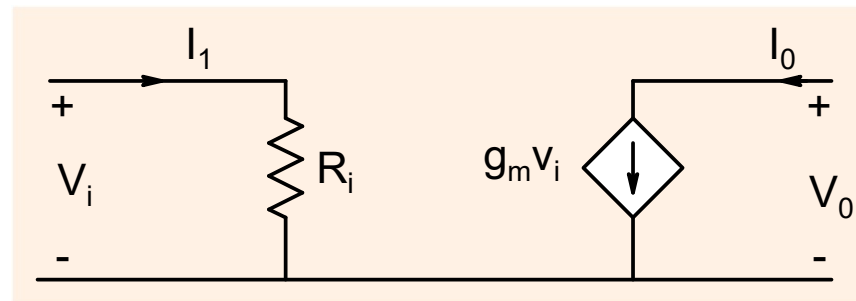
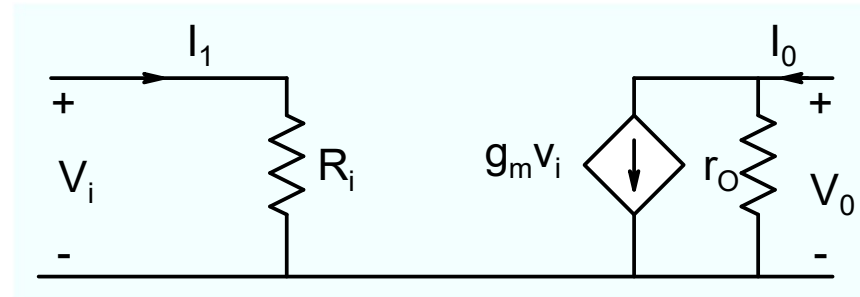


Current I_O is much more sensitive to V_{IN} than V_O



$$g_m r_o \gg 1$$

In the ideal case r_o is infinite



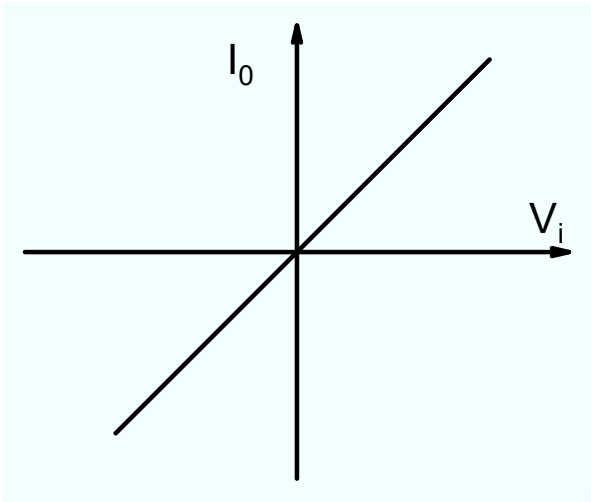
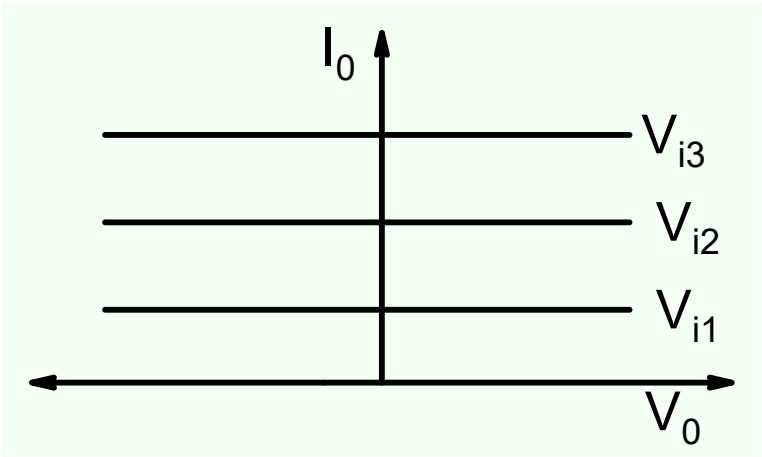
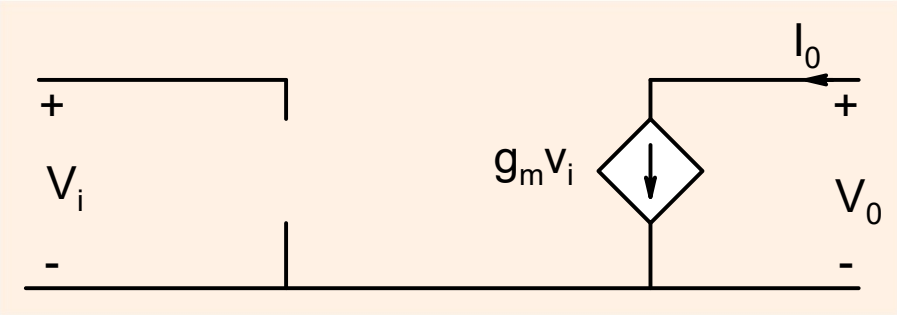
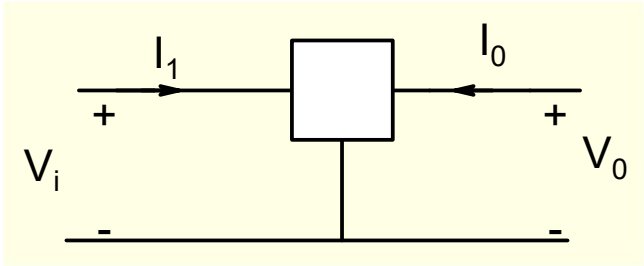
$$A_V = \frac{V_o}{V_s} = -g_m r_o \times \frac{R_L}{r_o + R_L} \times \frac{R_i}{R_i + R_S} = -g_m R_L \times \frac{R_i}{R_i + R_S}$$

We would ideally like input resistance R_i to be infinite as well !

$$A_V = -g_m R_L$$

Note that we have power gain as well which is essential for calling a device as an Amplifier

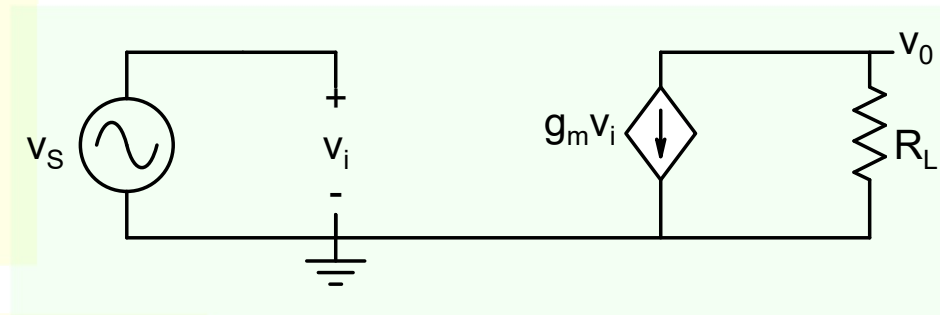
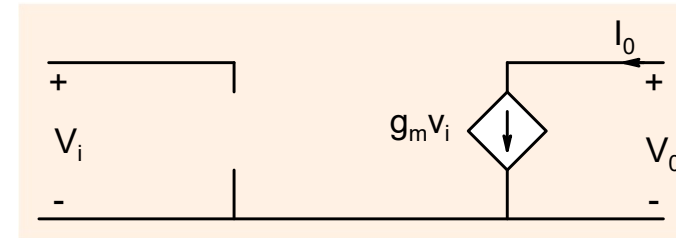
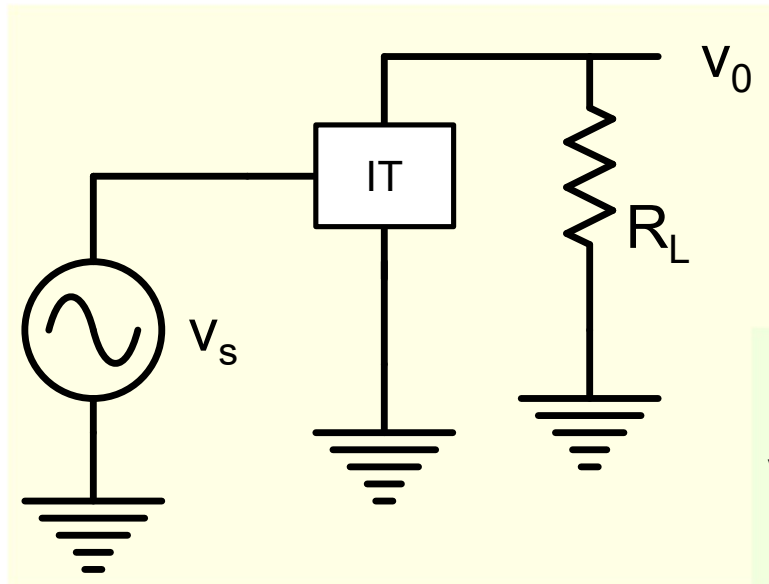
An ideal 3-terminal device for Voltage Amplification



Ideal Transistor Characteristics

Ideal Transistor (IT)

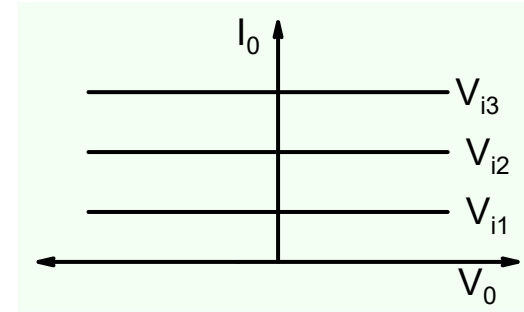
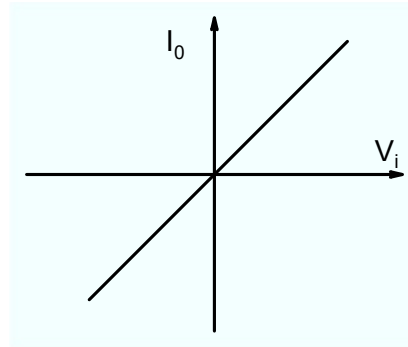
Making a voltage amplifier with an ideal transistor is straightforward



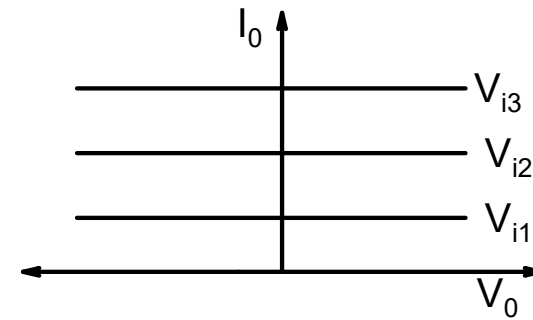
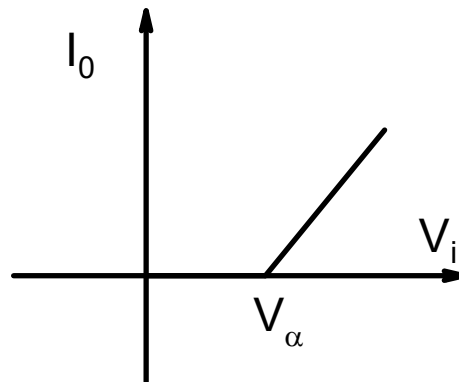
$$A_V = \frac{v_o}{v_s} = -g_m R_L$$

In practice there is no element which has the characteristics of ideal transistor !

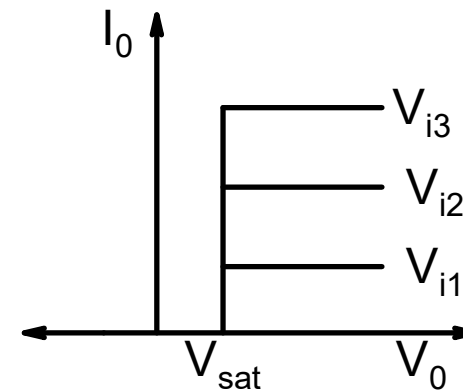
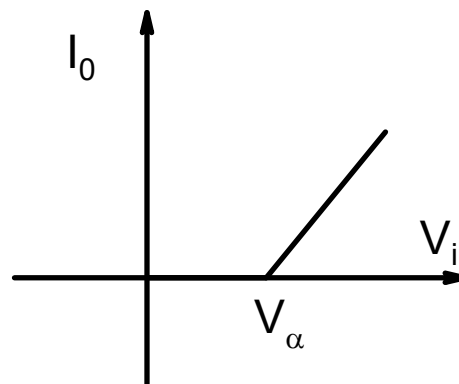
Ideal transistor



Device X

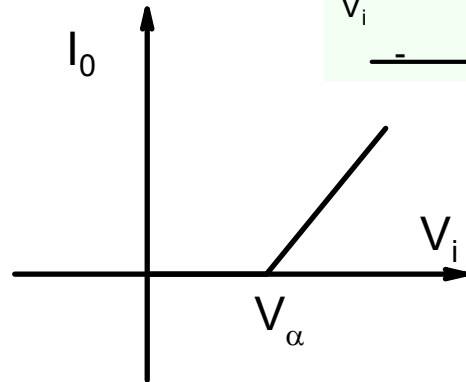
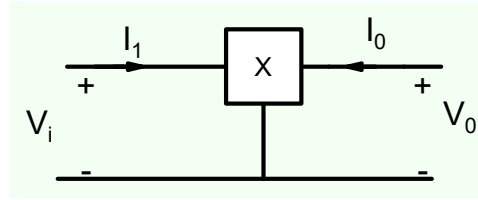


Device Y



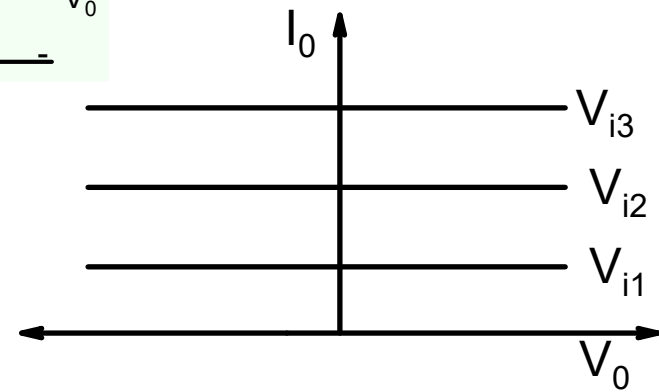
How do we use elements such as X, Y etc to make amplifiers?

Device X

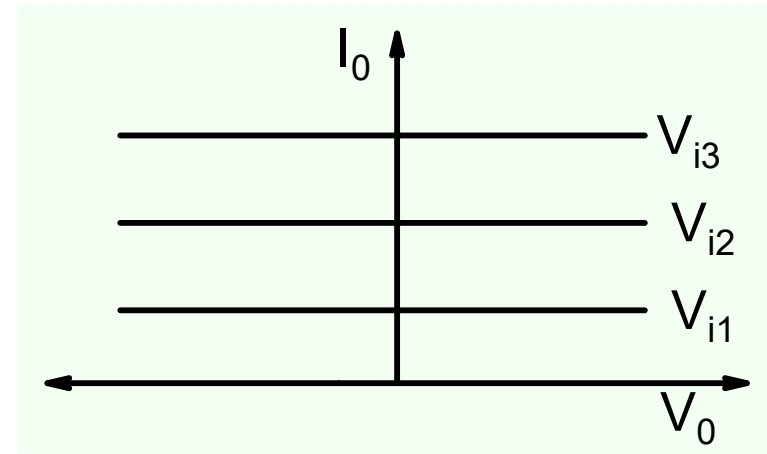
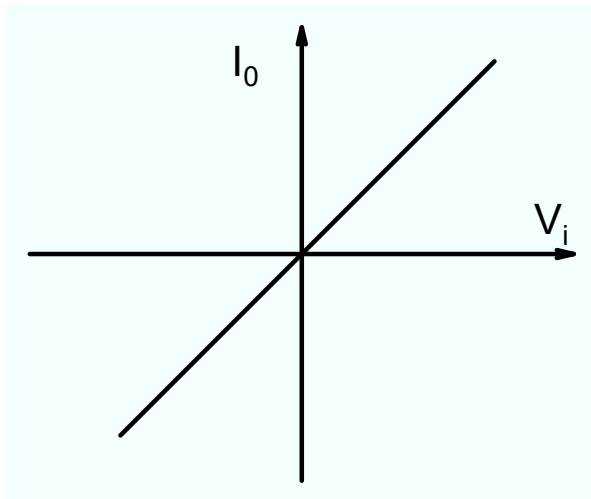


$$I_o = 0 \quad \text{for } V_i \leq V_\alpha$$

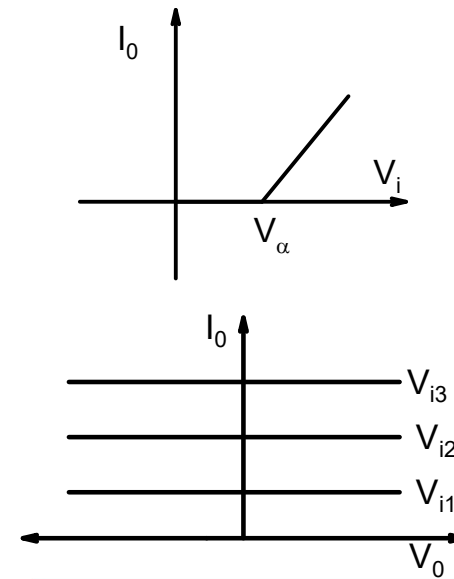
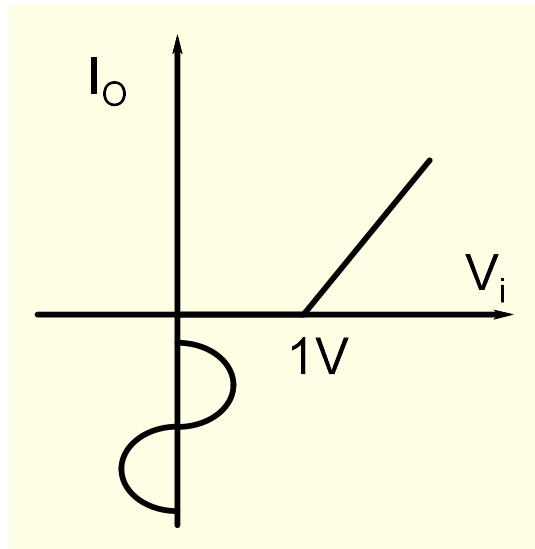
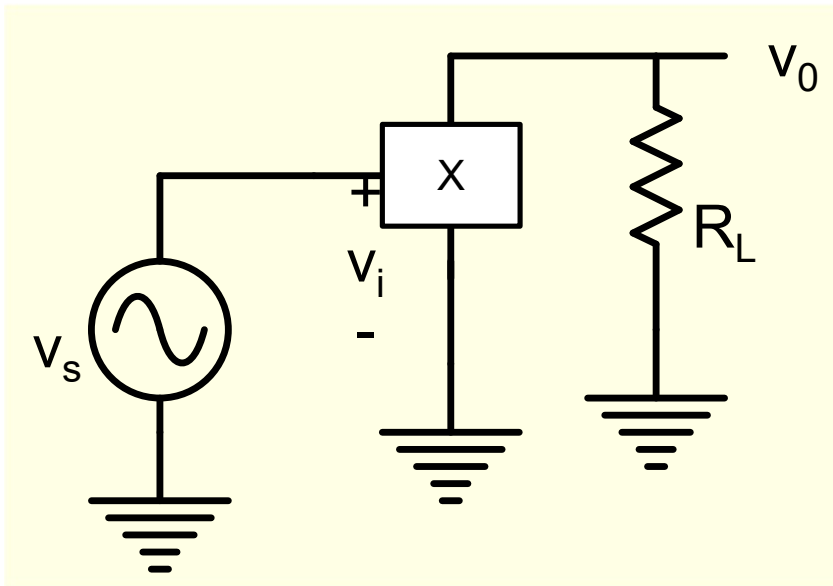
$$= g_m \times (V_i - V_\alpha) \quad \text{for } V_i > V_\alpha$$



Ideal Characteristics



How do we use device X to make an amplifier?



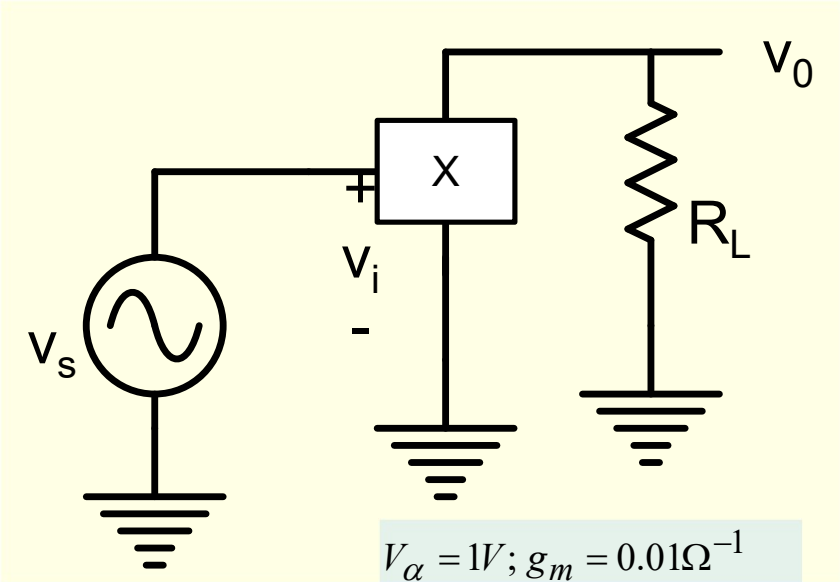
$$V_{\alpha} = 1V; g_m = 0.01\Omega^{-1}$$

$$R_L = 1K; v_s = 0.5V \sin \omega t$$

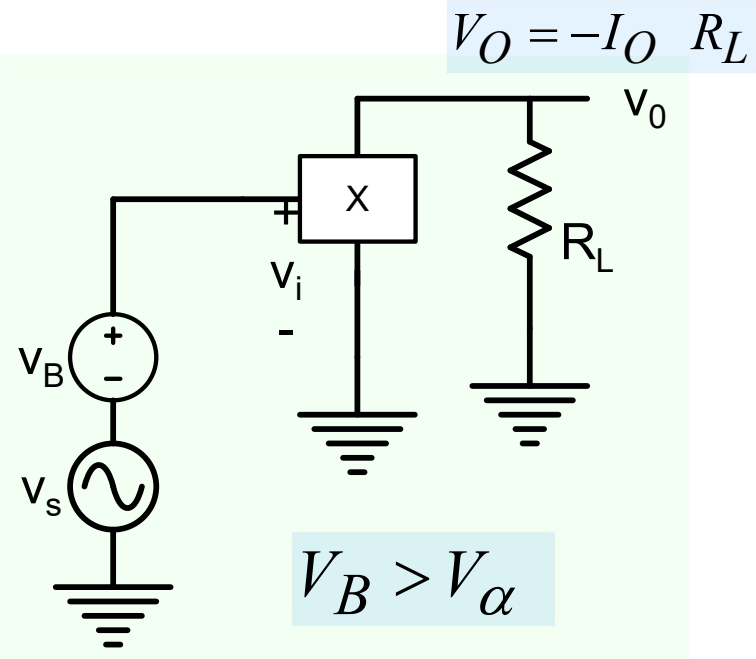
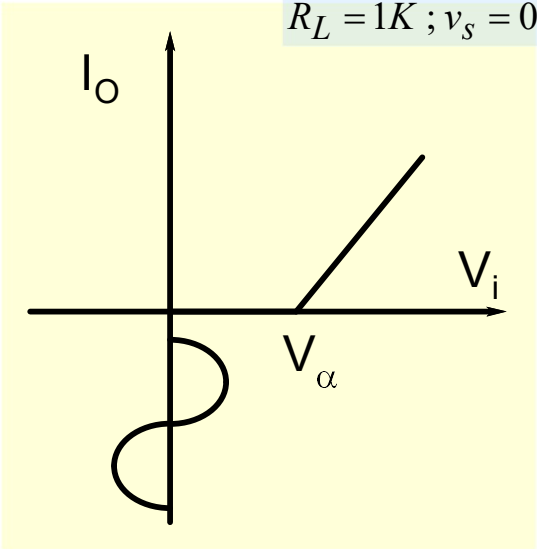
$$I_O = 0 \Rightarrow V_O = 0$$

No Amplification

How do we use device X to make an Amplifier?

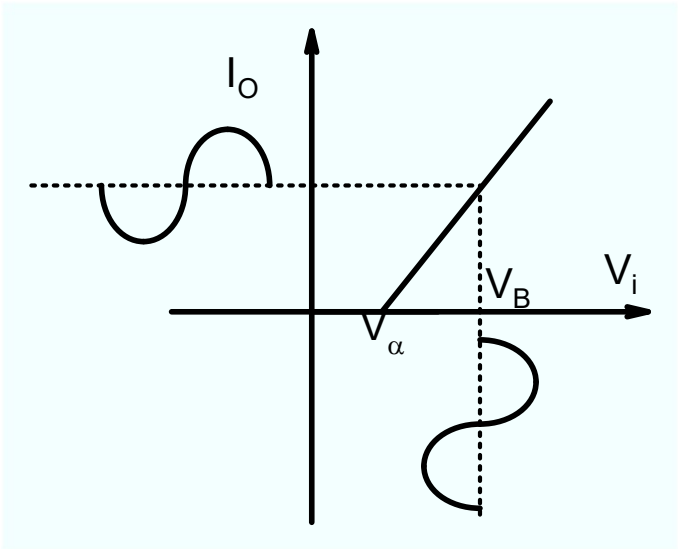


$V_{\alpha} = 1V; g_m = 0.01\Omega^{-1}$
 $R_L = 1K; v_s = 0.5V \sin \omega t$

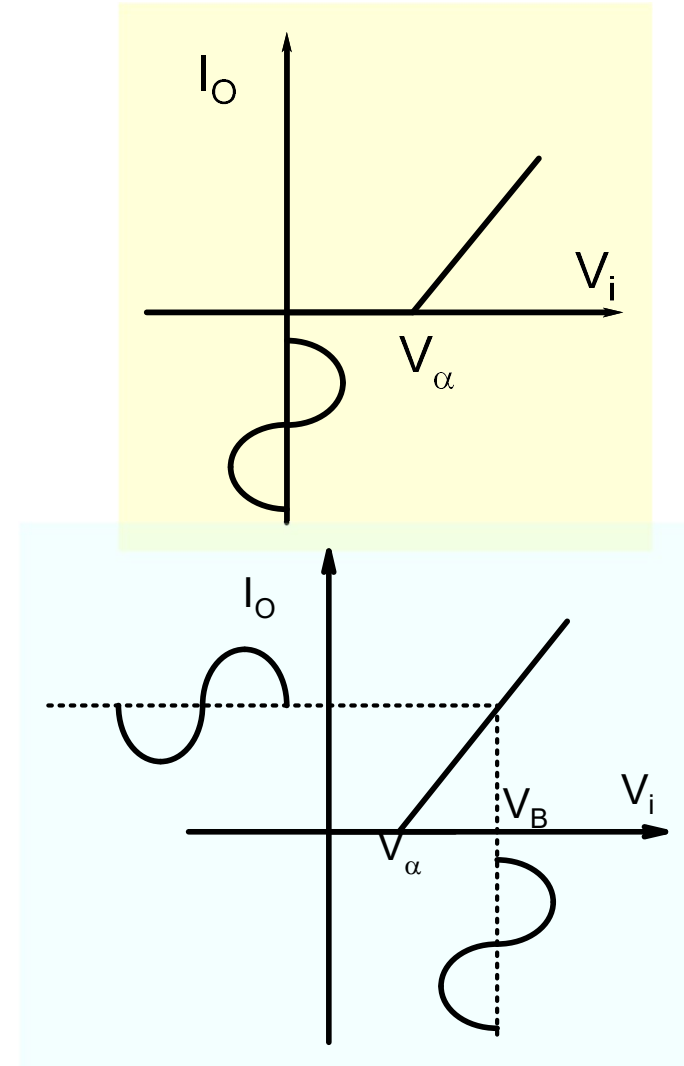
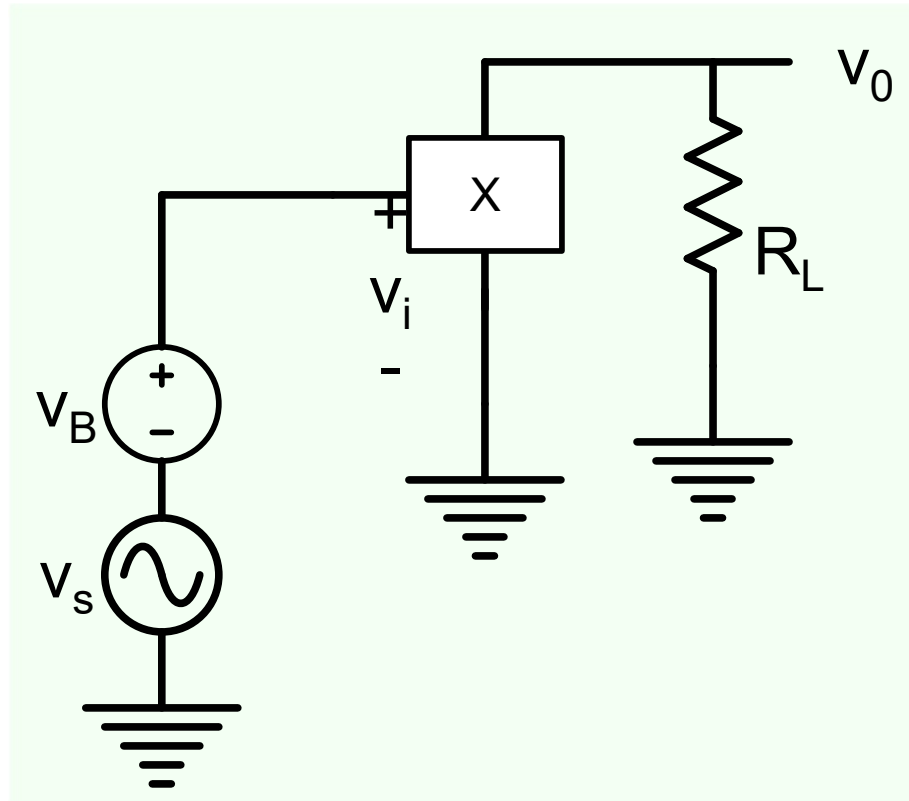


$V_O = -I_O R_L$

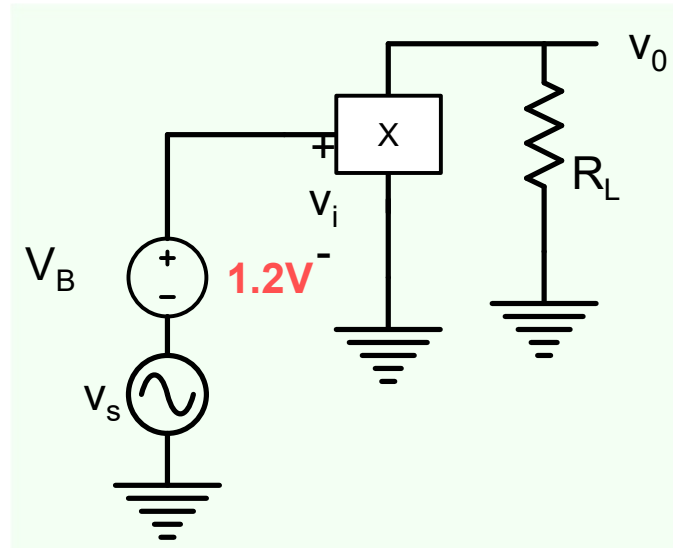
$V_B > V_{\alpha}$



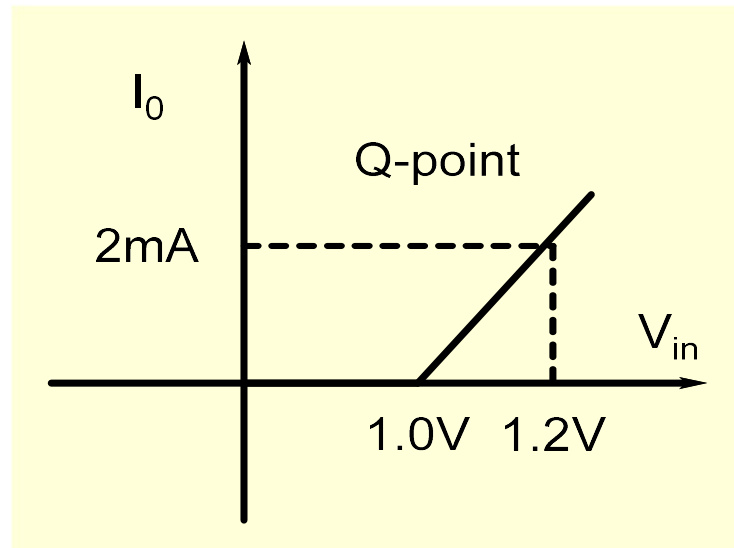
When only a part of device characteristics is suitable for amplification, then we need to push the device into that region by applying suitable bias voltages. This process is called **BIASING**



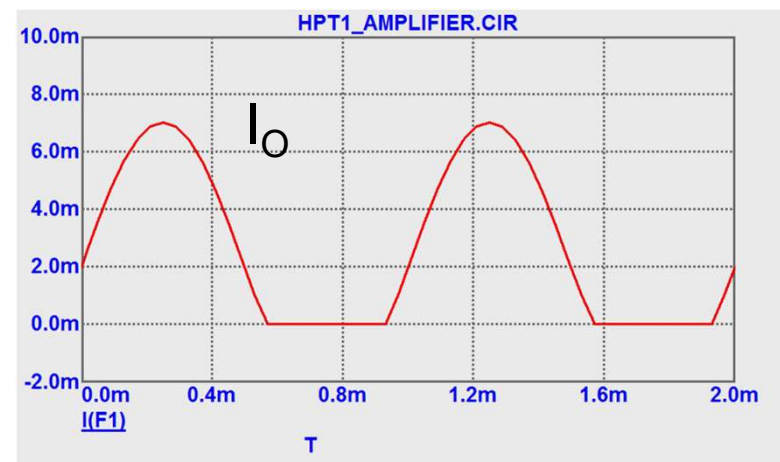
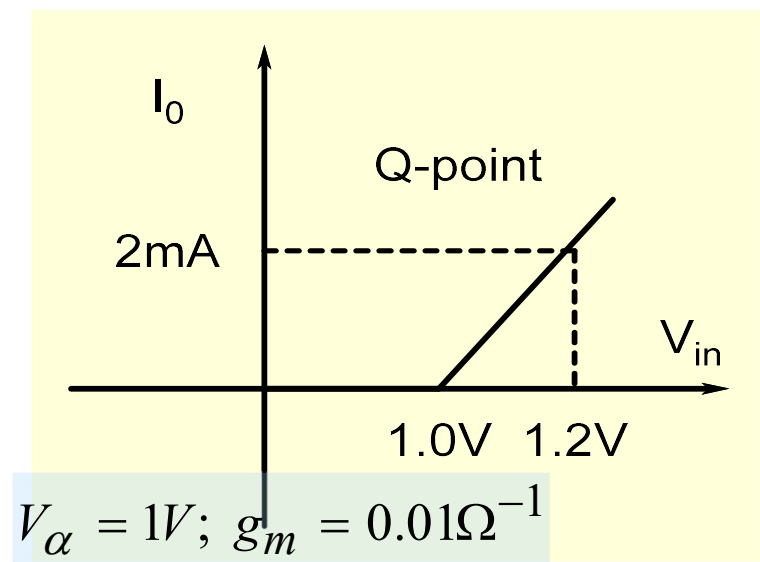
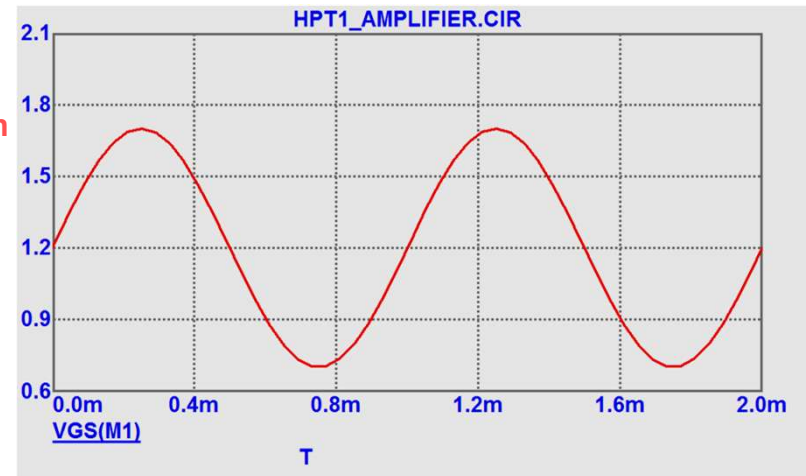
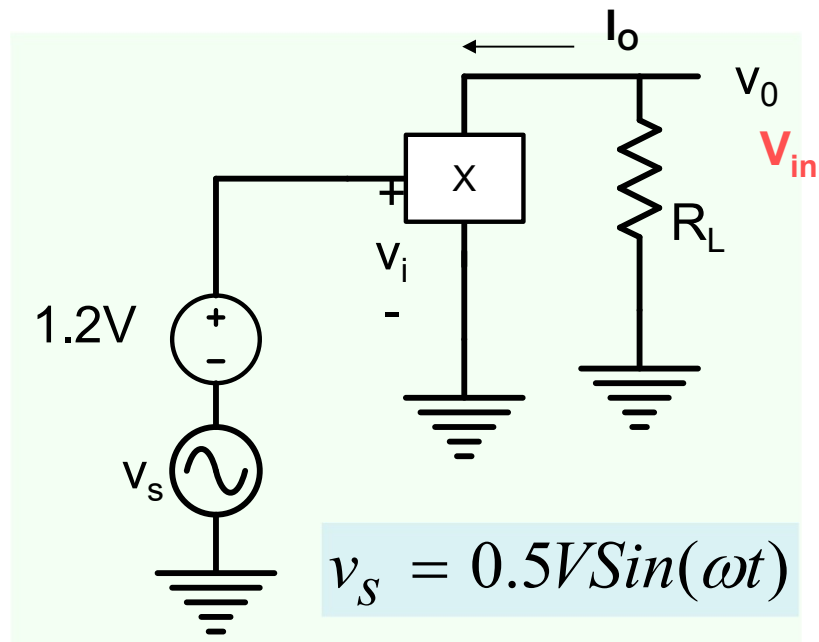
How should one choose the bias voltage V_B ?



$$v_s = 0.5V \sin \omega t$$

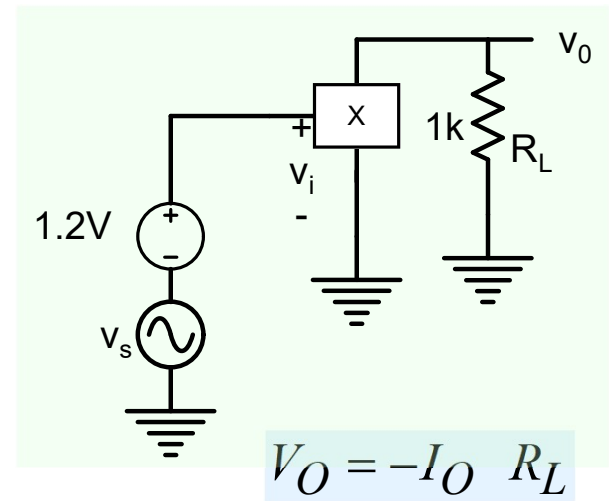
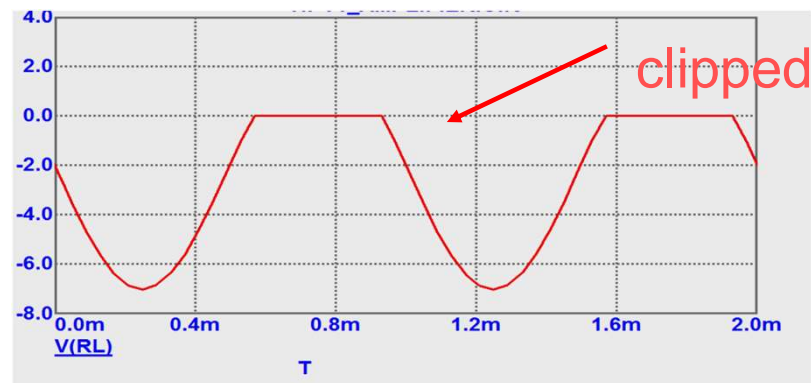
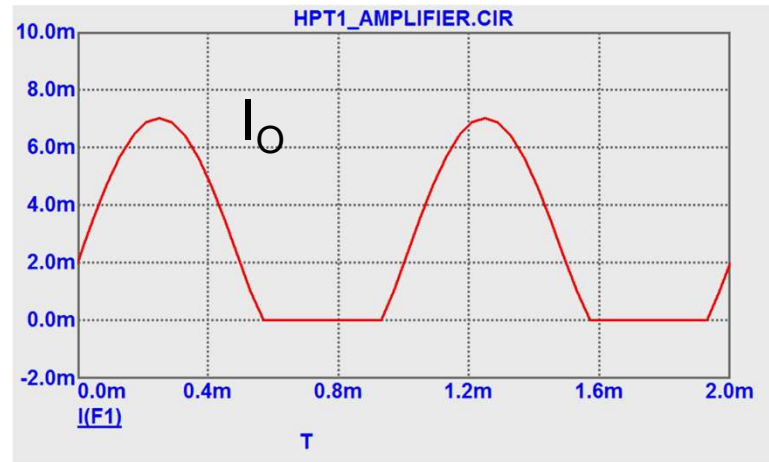


Quiescent point or Bias point



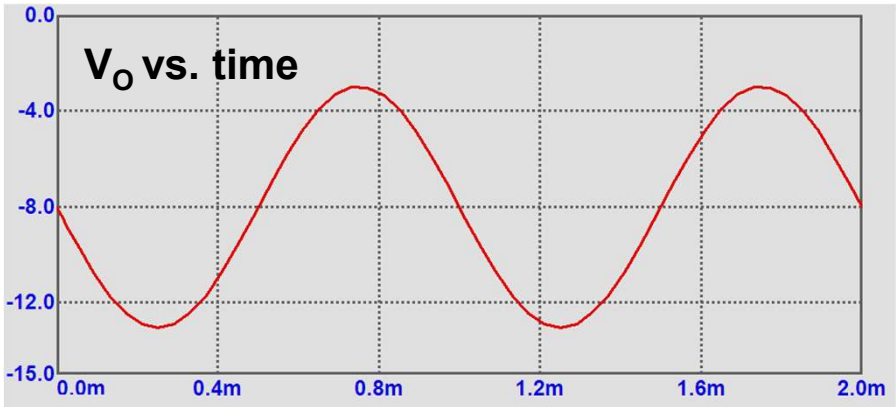
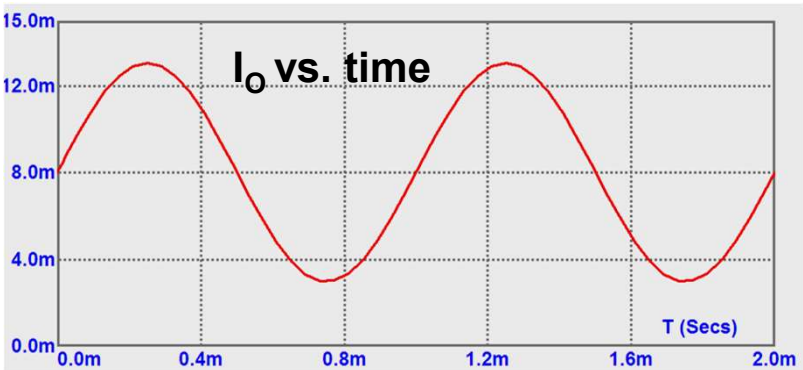
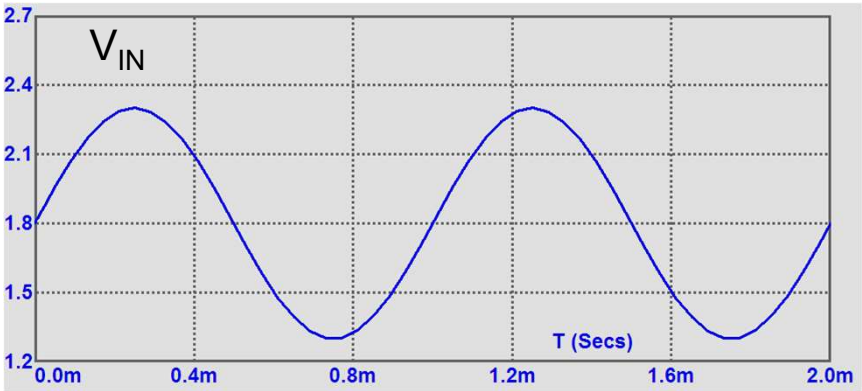
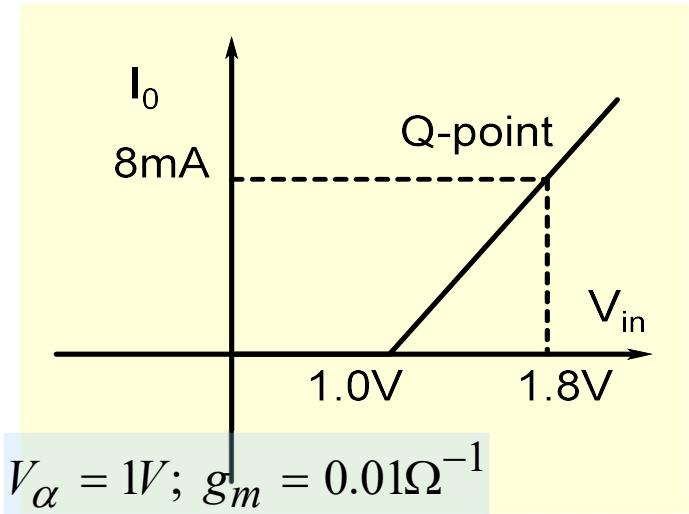
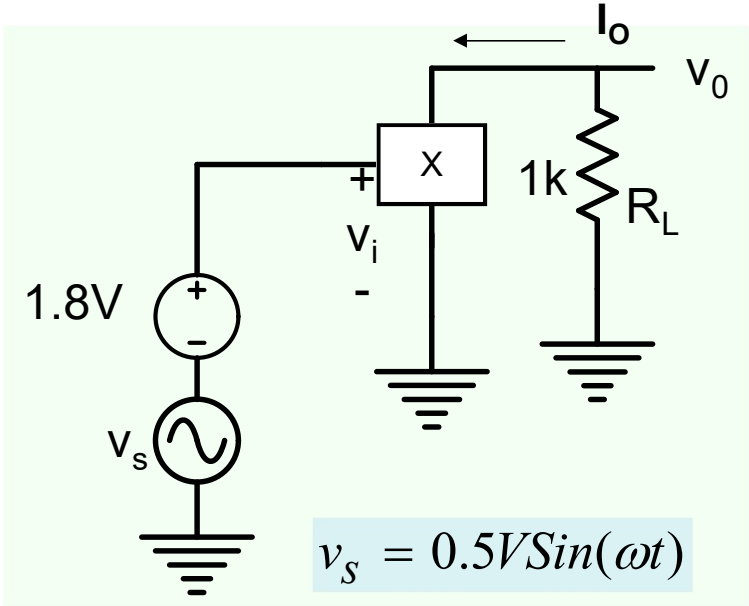
$$V_O = -I_O R_L$$

Output voltage is distorted !

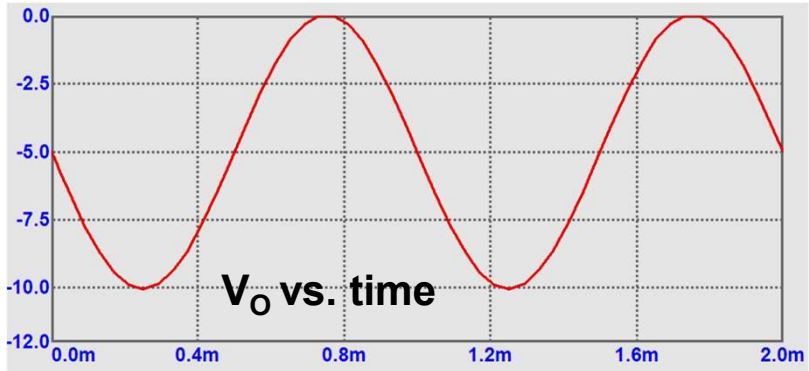
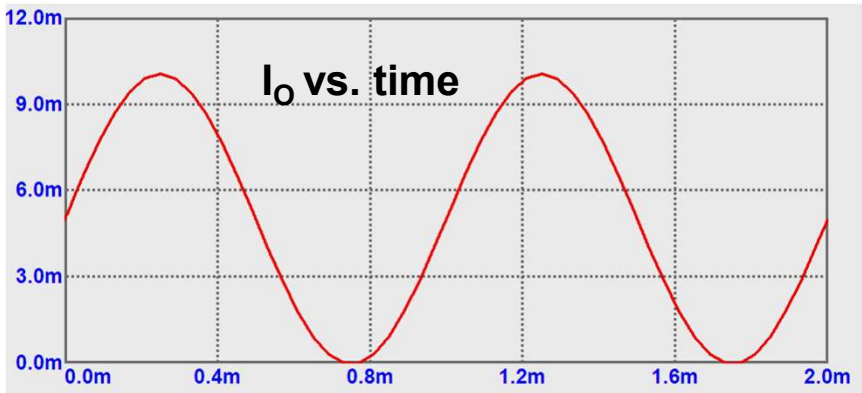
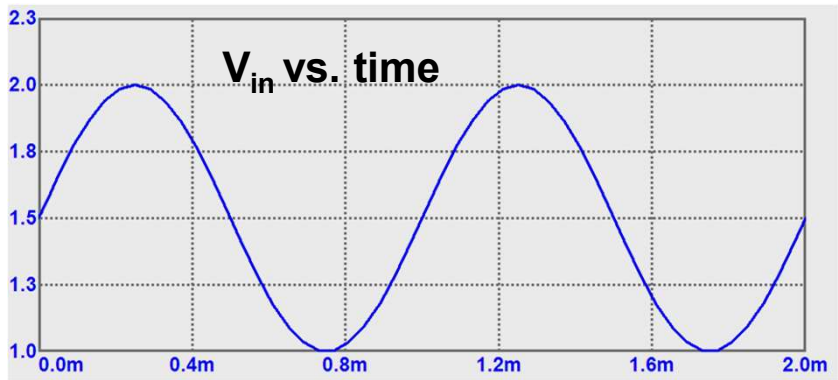
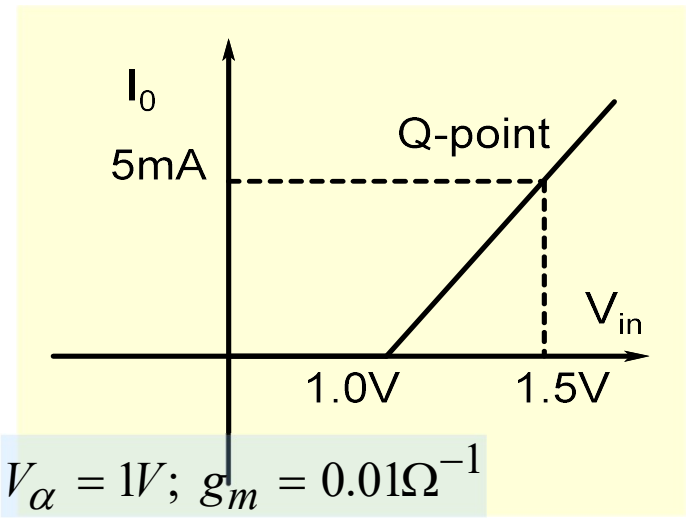
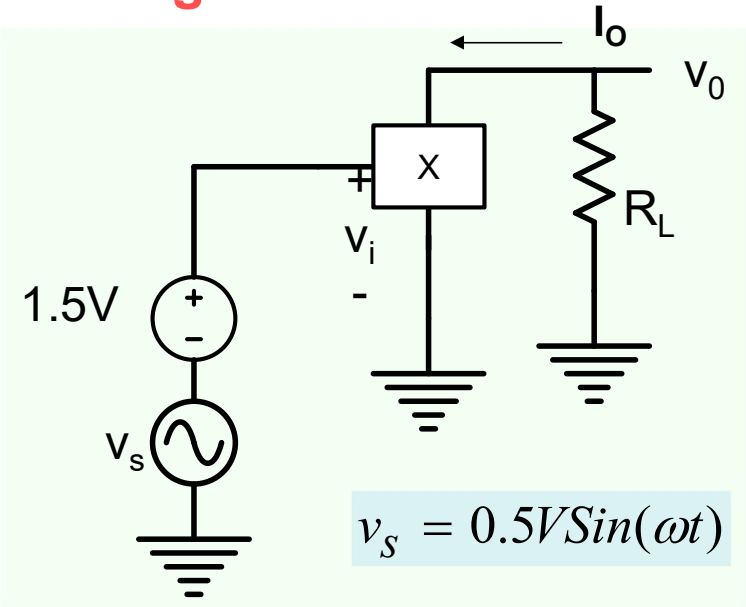


Need to choose a proper value of biasing Voltage

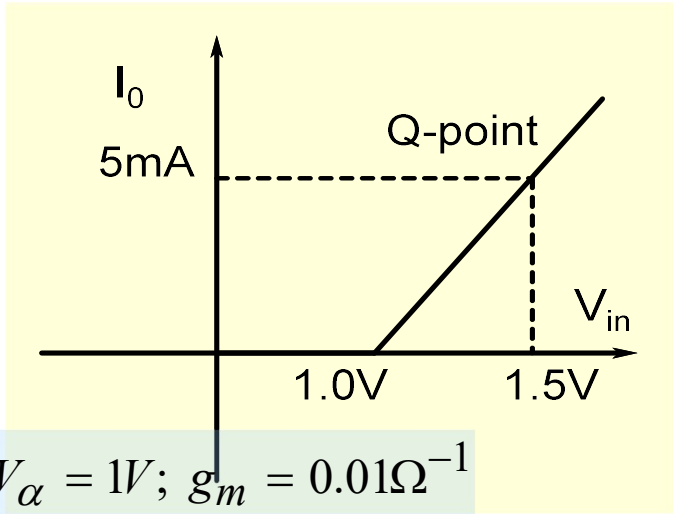
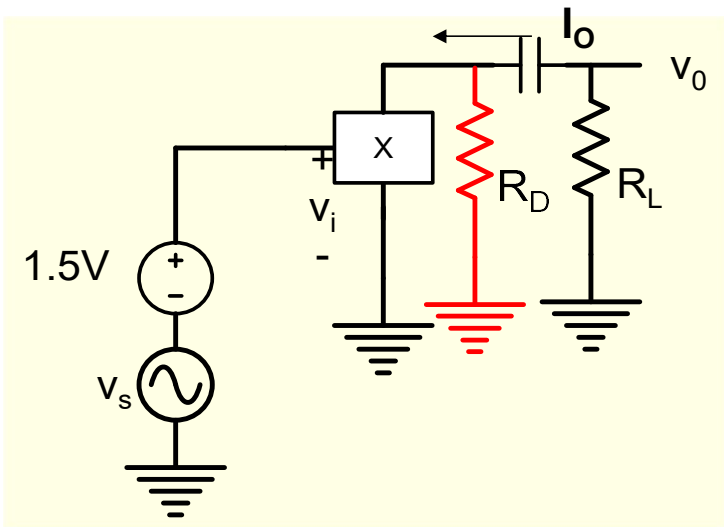
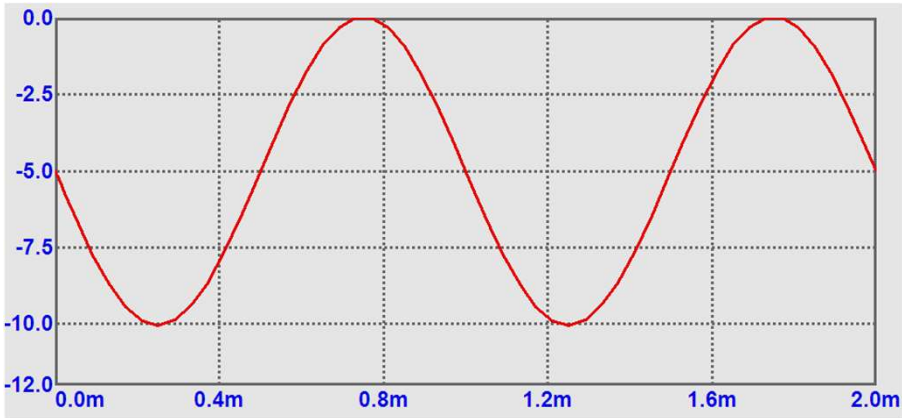
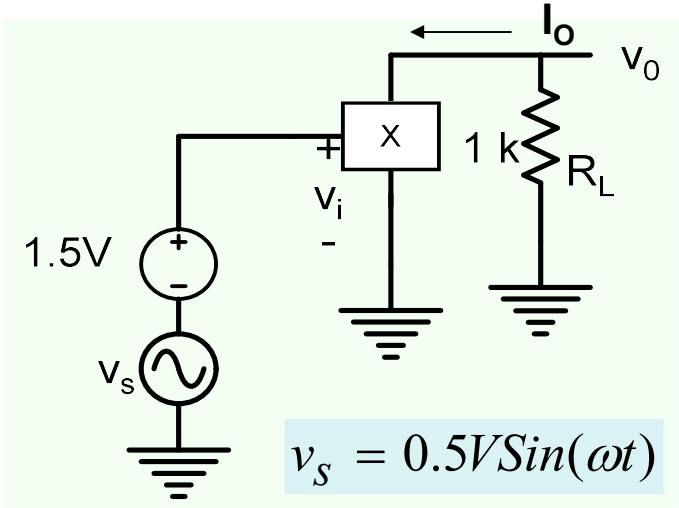
Unnecessary Power Dissipation

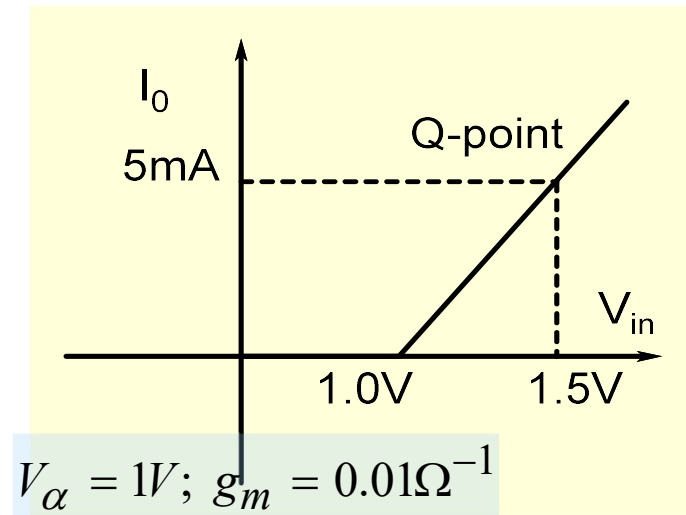
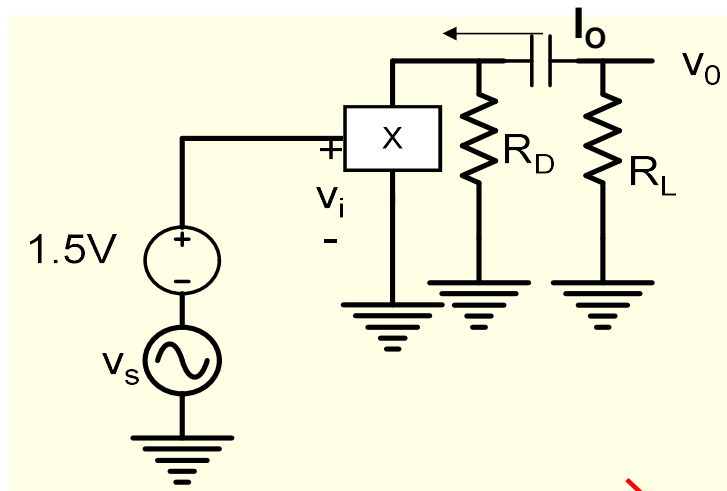


Optimum Biasing ?



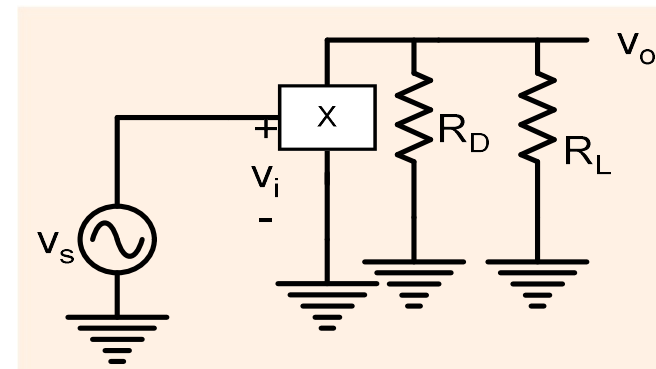
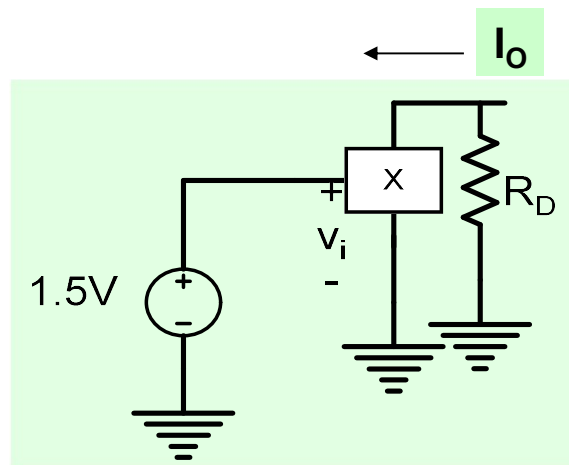
How do we get rid of unwanted dc voltage at the output ?



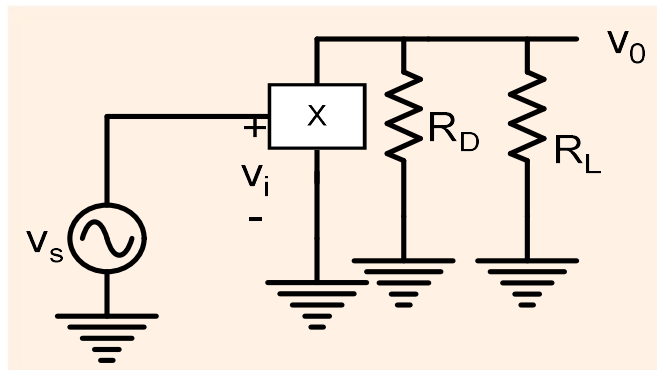


dc

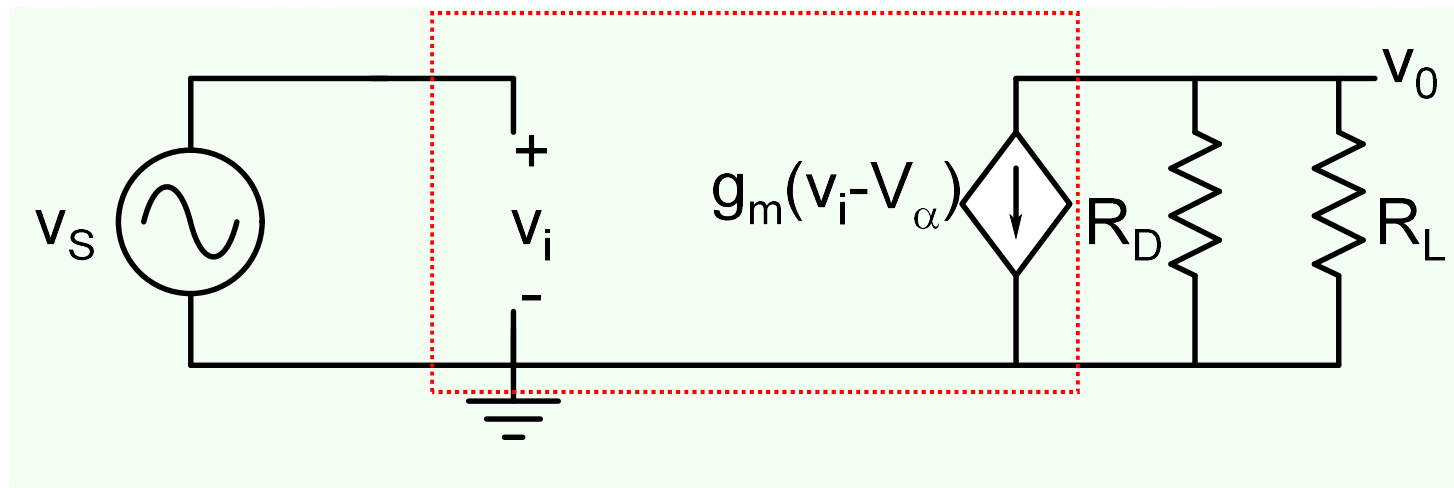
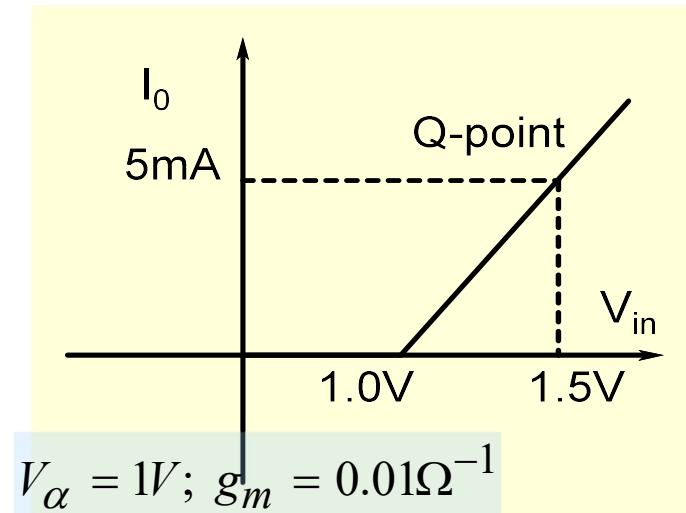
ac (signal)



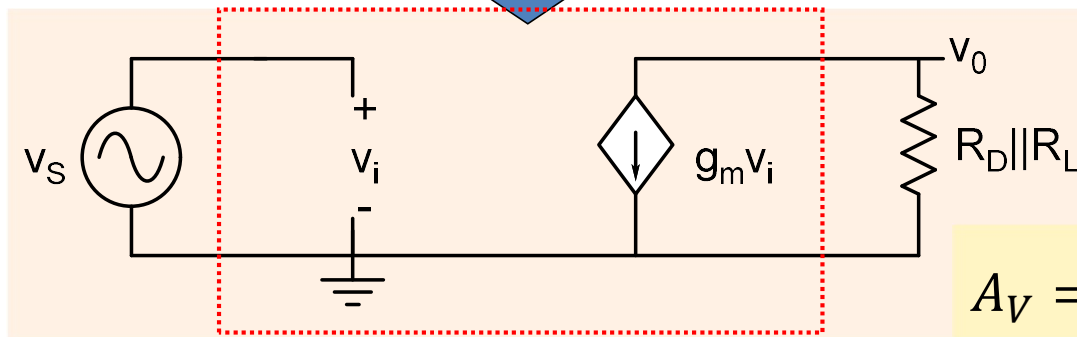
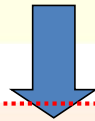
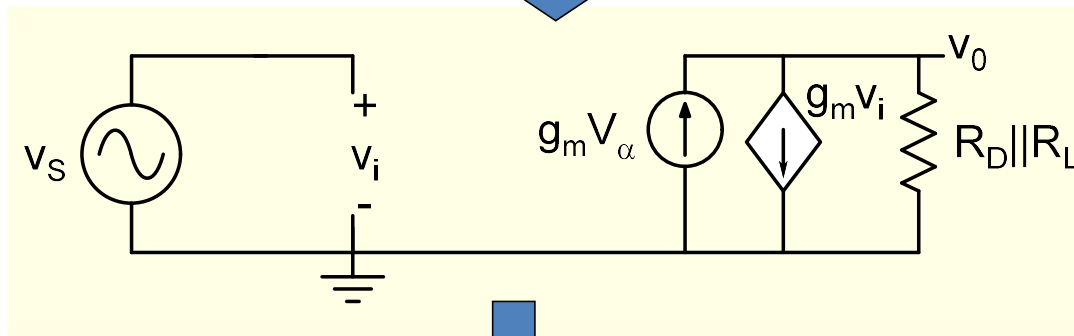
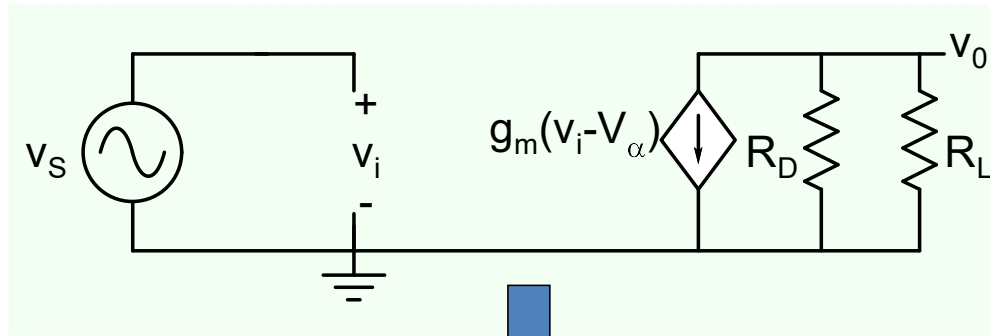
Capacitor is chosen large enough so that at the signal frequency $1/j\omega C \sim 0$.



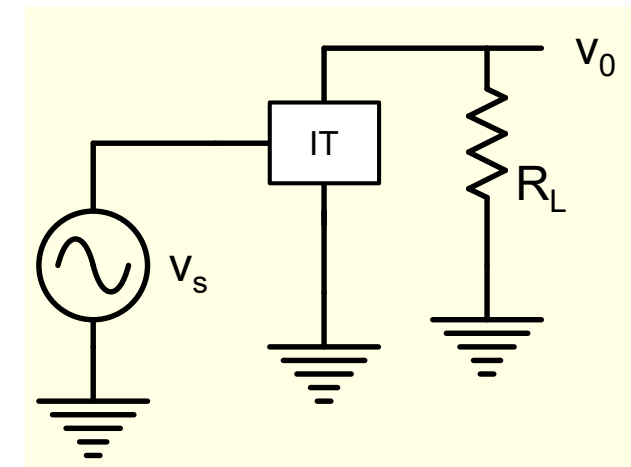
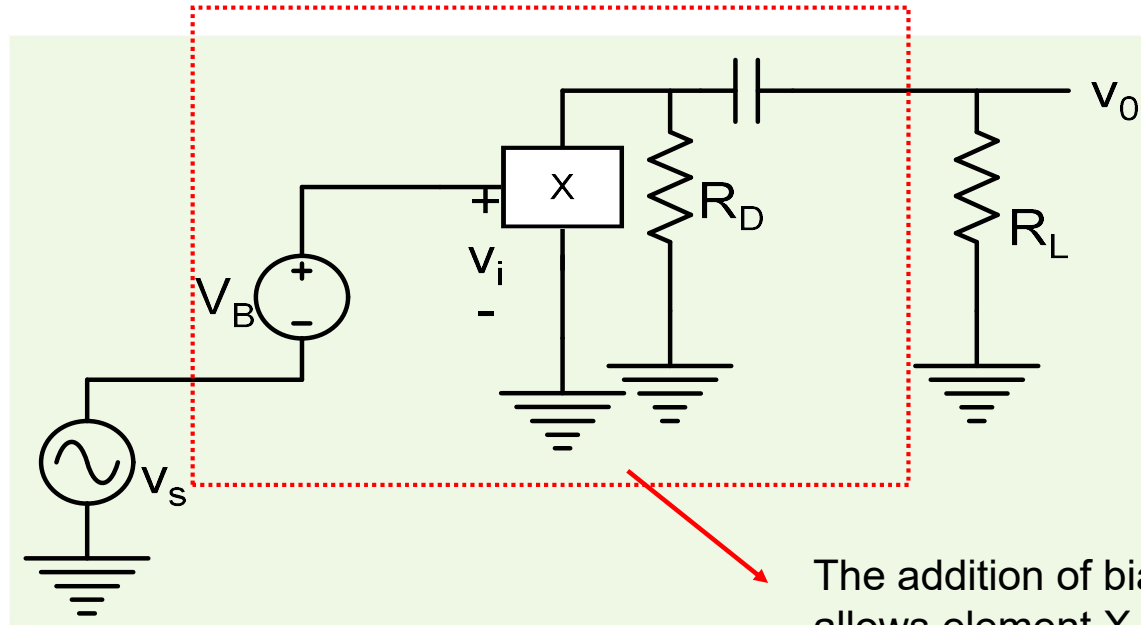
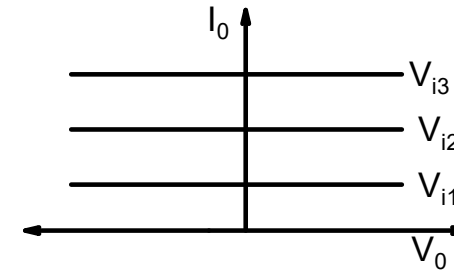
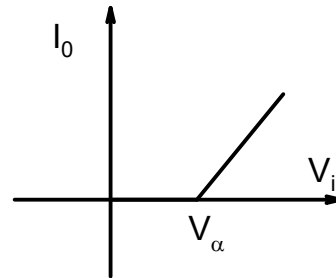
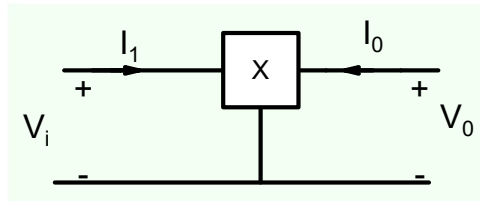
$$I_o = g_m \times (V_i - V_\alpha) \text{ for } V_i > V_\alpha$$



Ac Analysis

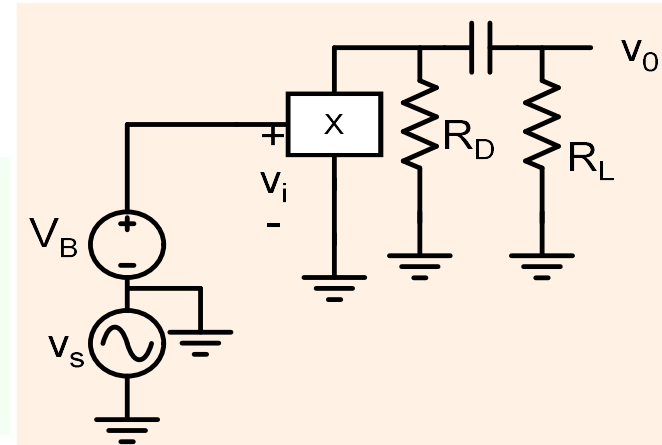
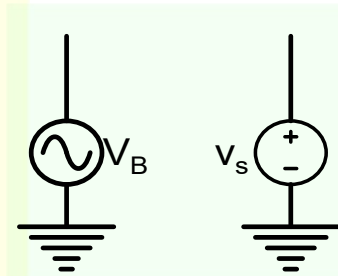
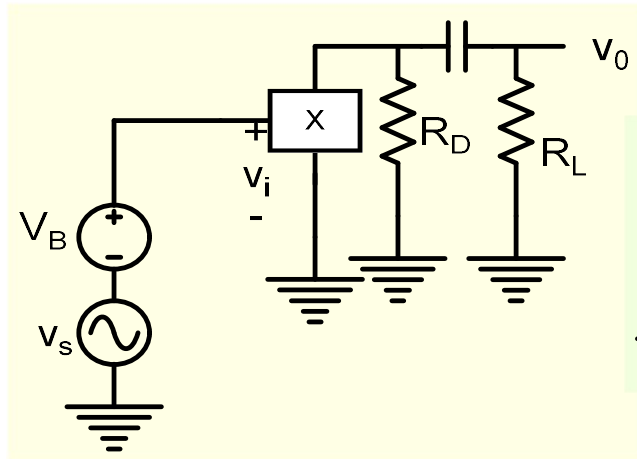


$$A_V = \frac{v_o}{v_s} = -g_m R_D \parallel R_L$$



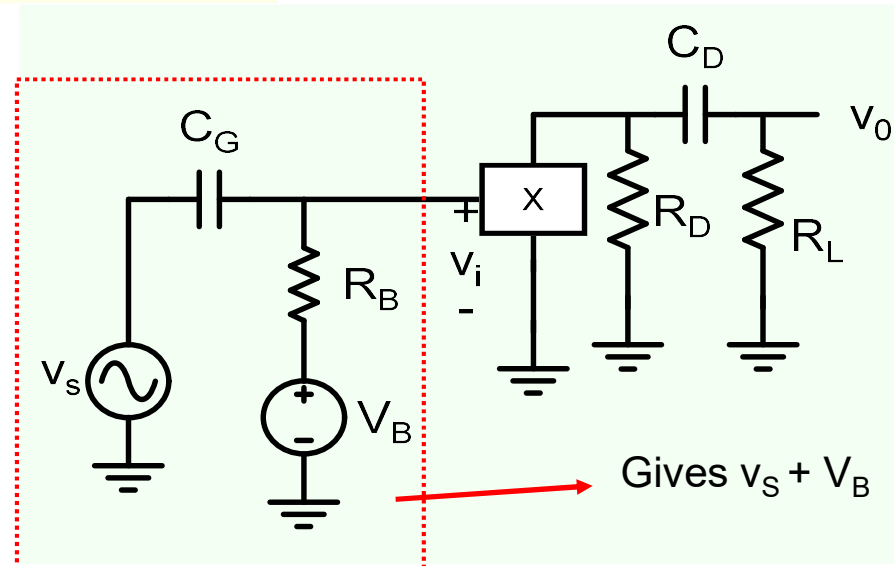
The addition of biasing network allows element X to appear as an ideal transistor to the signal source

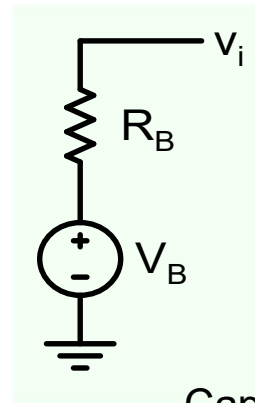
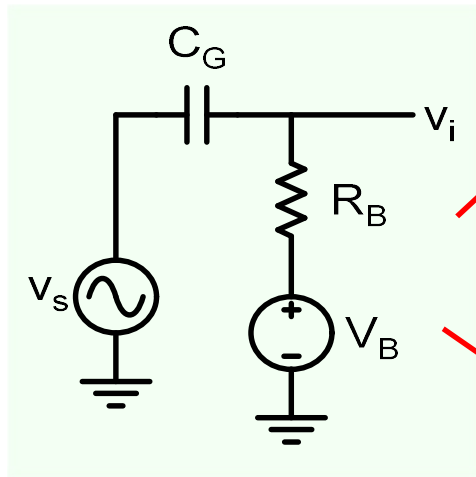
What happens if both dc voltage source and signal source have one terminal as ground?



Shorts the signal source

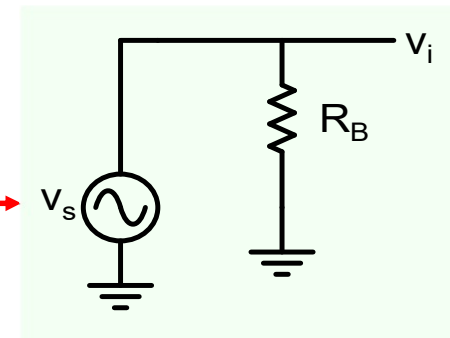
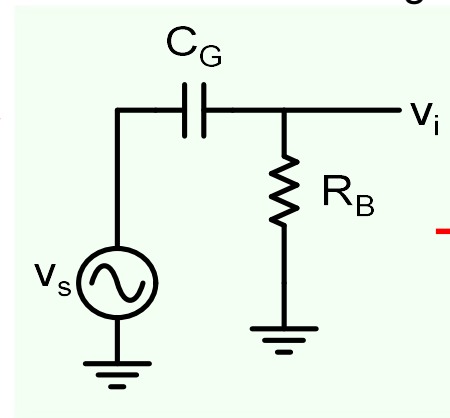
Solution





$$v_i = V_B$$

Capacitor is chosen large enough so that at the signal frequency $1/j\omega C \sim 0$.



$$v_i = v_s$$

$$v_i(\text{total}) = v_s + V_B$$

Note the role of R_B

Amplifier Schematic

